

Vishay Siliconix

P-Channel 8 V (D-S) MOSFET

DESCRIPTION

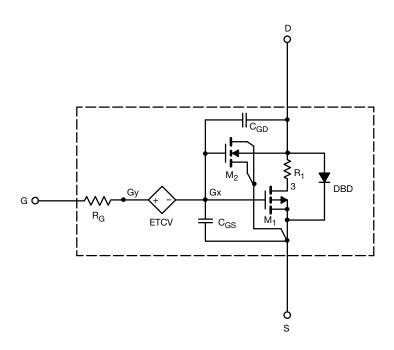
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the - 55 °C to + 125 °C temperature ranges under the pulsed 0 V to 5 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched $C_{\rm gd}$ model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the 55 °C to + 125 °C Temperature Range
- · Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



SPICE Device Model SiA427DJ

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SPECIFICATIONS T _J = 25 °C, unless otherwise noted					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = -250 \mu A$	0.55	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 8.2 A	0.012	0.013	Ω
		V _{GS} = - 1.8 V, I _D = - 6.6 A	0.020	0.021	
Forward Transconductance ^a	9fs	V _{DS} = - 4 V, I _D = - 8.2 A	41	37	S
Diode Forward Voltage	V_{SD}	I _S = - 9.8 A	- 0.86	- 0.80	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = - 4 V, V _{GS} = 0 V, f = 1 MHz	2420	2300	pF
Output Capacitance	C _{oss}		793	735	
Reverse Transfer Capacitance	C _{rss}		743	690	
Total Gate Charge	Qg	V _{DS} = - 4 V, V _{GS} = - 5 V, I _D = - 10 A	28	33	
			25	30	0
Gate-Source Charge	Q _{gs}	$V_{DS} = -4 \text{ V}, V_{GS} = -4.5 \text{ V}, I_{D} = -10 \text{ A}$	3	3	nC
Gate-Drain Charge	Q _{ad}		6.6	6.6	

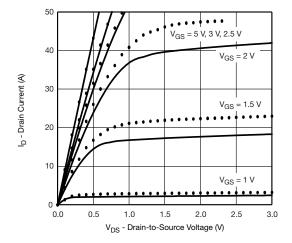
Notes

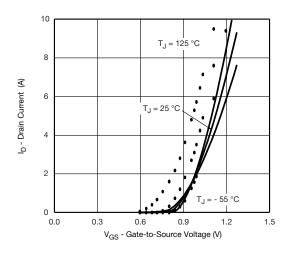
- a. Pulse test; pulse width $\leq 300~\mu s,\,duty~cycle \leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

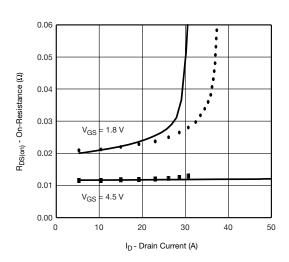
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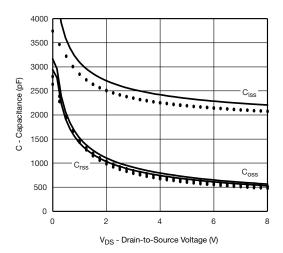
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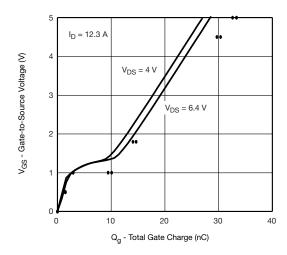
COMPARISON OF MODEL WITH MEASURED DATA $T_J = 25~^{\circ}\text{C}$, unless otherwise noted

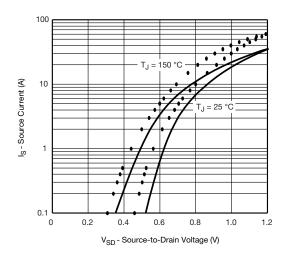












NoteDots and squares represent measured data.



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